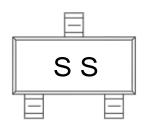


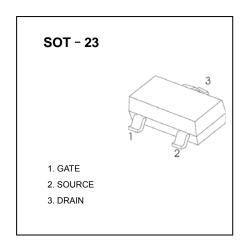
N-Channel MOSFET

■ Features

- VDS (V) = 50V
- ID = 300 mA (VGS = 10V)
- ullet RDS(ON) < 2.5 Ω (VGS = 10V)
- ullet RDS(ON) $< 3.5 \,\Omega$ (VGS =2.5V)
- Low On-Resistance
- ESD Rating: 1.5KV HBM

MARKING





■ Absolute Maximum Ratings Ta = 25°C

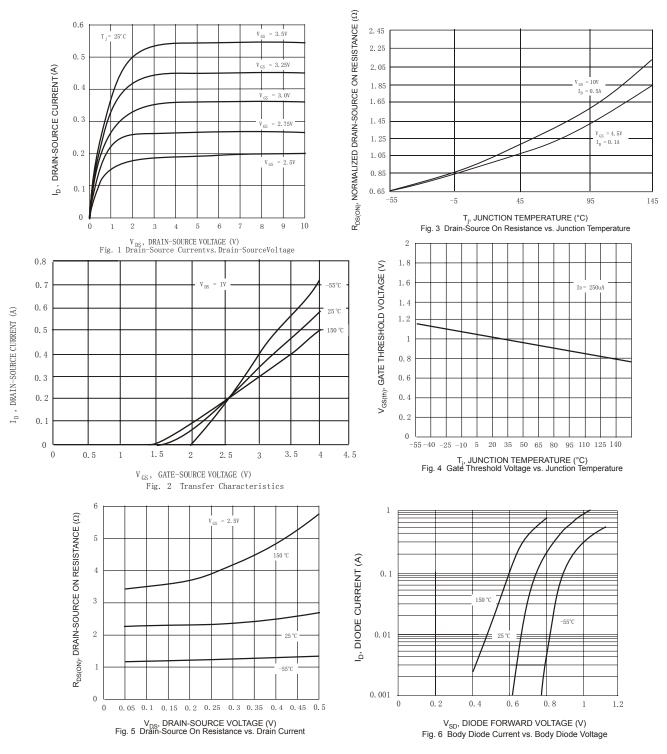
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	VDS	50	
Drain-Gate Voltage Rgs≤ 20KΩ	VDG	50	V
Gate-Source Voltage	Vgs	±20	
Continuous Drain Current	ΙD	300	mA
Power Dissipation	PD	300	mW
Thermal Resistance.Junction- to-Ambient	RthJA	417	°C/W
Junction Temperature	TJ	150	°C
Storage Temperature Range	Tstg	-55 to 150	C

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Drain-Source Breakdown Voltage	VDSS	ID=250 μ A, VGS=0V	50			V	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =50V, V _{GS} =0V			0.5	uA	
Gate-Body Leakage Current	Igss	V _{DS} =0V, V _{GS} =±20V			±10	uA	
Gate Threshold Voltage	VGS(th)	VDS=VGS , ID=250 μ A	0.7		1.5	V	
Static Drain-Source On-Resistance	Rds(on)	Vgs=10V, Ip=500mA			2.5	Ω	
Static Drain-Source Off-Resistance	RDS(OH)	Vgs=2.5V, Ip=500mA			3.5		
Forward Transconductance	gFS	Vps=25V, Ip=0.3A,f=1KHz	100			mS	
Input Capacitance	Ciss				50		
Output Capacitance	Coss	Vgs=0V, Vps=10V, f=1MHz			25	pF	
Reverse Transfer Capacitance	Crss				8		
Turn-On DelayTime	td(on)	VDS=30V, ID=0.3A,Rg=50Ω			20	ns	
Turn-Off DelayTime	td(off)	VD3-30V, ID-0.3A,NG-30 s2			20	115	

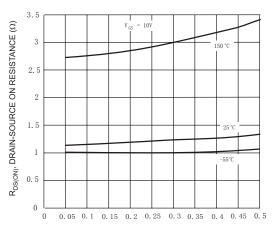


■ Typical Characterisitics

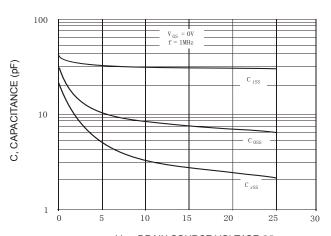




■ Typical Characterisitics



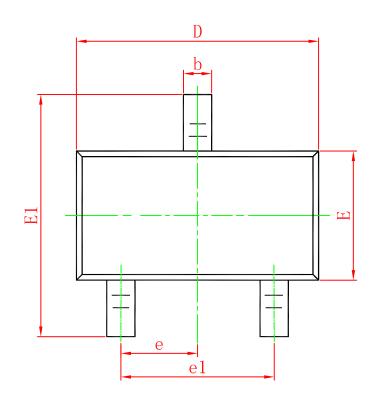
I_D, DRAIN CURRENT (A) Fig. 7 Drain-Source On Resistance vs. Drain Current

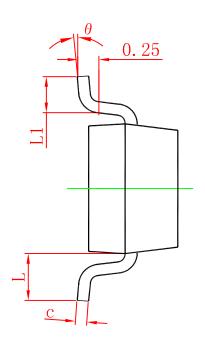


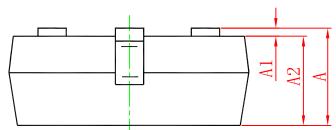
 $\rm V_{DS}$, DRAIN SOURCE VOLTAGE (V) Fig. 8 Capacitance vs. Drain Source Voltage



SOT-23 PACKAGE OUTLINE DIMENSIONS







Symbol	Dimensions	In Millimeters	Dimension	Dimensions In Inches		
	Min.	Max.	Min.	Max.		
Α	0.900	1.150	0.035	0.045		
A1	0.000	0.100	0.000	0.004		
A2	0.900	1.050	0.035	0.041		
b	0.300	0.500	0.012	0.020		
С	0.080	0.150	0.003	0.006		
D	2.800	3.000	0.110	0.118		
E	1.200	1.400	0.047	0.055		
E1	2.250	2.550	0.089	0.100		
е	0.950 TYP.		0.037 TYP.			
e1	1.800	2.000	0.071	0.079		
L	0.550 REF.		0.022 REF.			
L1	0.300	0.500	0.012	0.020		
θ	0°	8°	0°	8°		